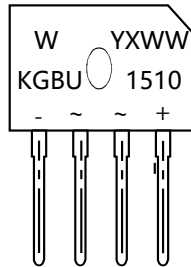


15A Surface Mount Schottky Bridge Rectifier



PINNING

PIN	DESCRIPTION
1	Input Pin (~)
2	Input Pin (~)
3	Output Anode (+)
4	Output Cathode (-)

Features

- Glass Passivated Chip Junction
- Reverse Voltage - 100 V
- Forward Current - 15A
- High Surge Current Capability
- Thermal welding performance:
260 °C/10sec

Applications

- Case: GBU
- Terminals: Solderable Per MIL-STD-750

Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

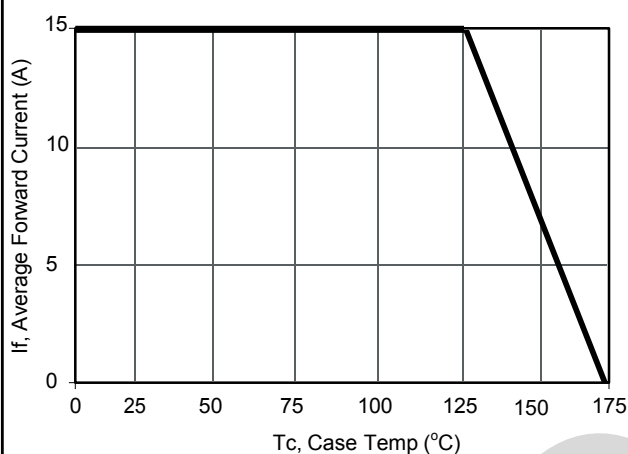
Parameter	Symbols	KGBU1510	Units
Maximum Repetitive Peak Reverse Voltage	VRRM	100	V
Maximum RMS voltage	VRMS	70	V
Maximum DC Blocking Voltage	VDC	100	V
Average Rectified Output Current	I _o	15.0	A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	IFSM	200	A
I ² t rating for fusing (1ms < t < 8.3ms)	I ² t	166	A ² S
Maximum Forward Voltage at 7.5 A	V _F	1.1	V
Maximum DC Reverse Current @TA=25 °C at Rated DC Blocking Voltage @TA=125 °C	I _R	5 500	μA
Typical Junction Capacitance (Note1)	C _j	70	pF
Operating and Storage Temperature Range	T _j , T _{stg}	-55 ~ +175	°C
Typical thermal resistance (Note 2)	R _{thJA} R _{thJL}	9.0 1.5	°C/W

Note: 1. Measured at 1MHz and applied reverse voltage of 4 VDC.

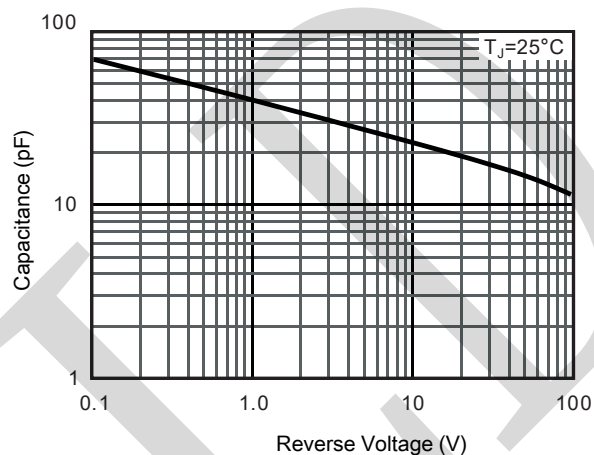
2. Thermal resistance junction to case, lead and ambient in accordance with JESD-51.

Unit mounted on glass-epoxy substrate with 1oz/ft² 20x20 mm copper pad per pin with heatsink

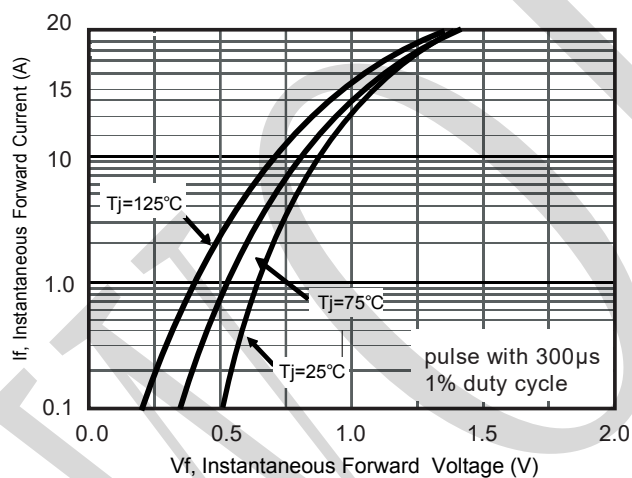
RATINGS AND CHARACTERISTICS CURVES (TA = 25 °C unless otherwise noted)



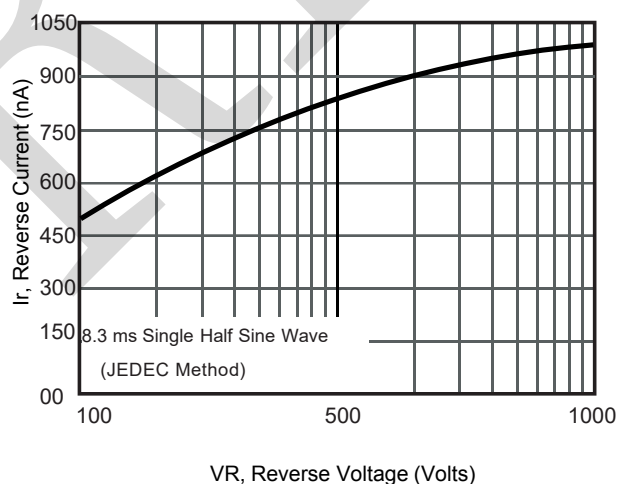
Current Derating, Case



Typical Junction Capacitance

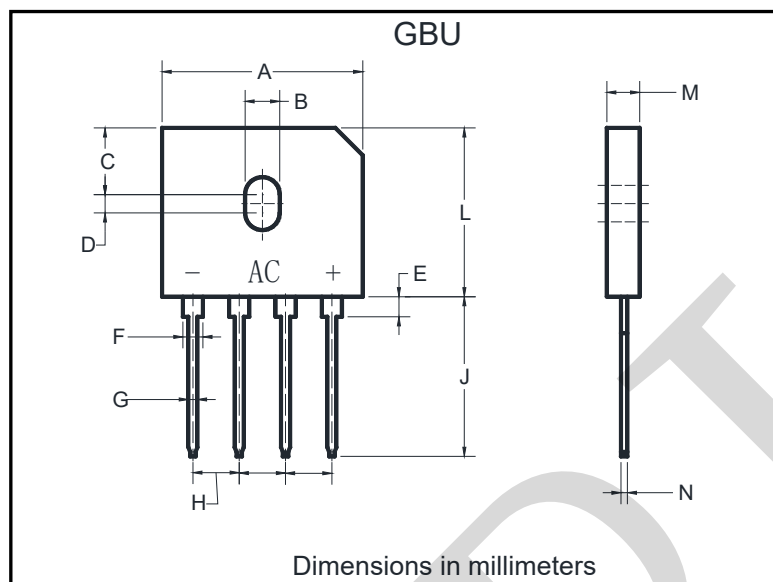


Typical Forward Voltage



Typical Reverse Current

PACKAGE OUTLINE DIMENSIONS



GBU		
Dim	Min	Max
A	21.70	22.50
B	3.40	4.10
C	7.40	8.00
D	1.65	2.26
E	2.25	2.85
F	2.05	2.4
G	1.02	1.37
H	4.83	5.43
J	17.0	18.6
L	18.3	18.9
M	3.30	3.66
N	0.46	0.66

